Advanced Process Control of Chemical Concentration for Solar Cell Manufacturing

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Abstract — Solar cell manufacturing requires many wet cleaning steps. Texturization is one of these steps. As a method for light trapping, the texturization step is very critical to assure high efficiency for cells based on both mono-crystalline and multi-crystalline silicon. In order to obtain stable and reproducible manufacturing processes, a reliable and accurate real-time measurement of the etching constituents becomes necessary. Chemical mixtures include: KOH/IPA, HF/HNO₃, HF/HCl. Other additives, e.g. surfactants are typically added to enhance the etch uniformity.

Index Terms — solar, Si content, texturization, concentration control, uniformity, utilization

I. INTRODUCTION

Although the chemical reaction is well known, the anisotropic etching of Si in alkaline solutions is a complex process. This is particularly true in the solar industry where a large mass of silicon is typically introduced into the etch bath. The etch by-products (silicates) affect the balance of the etching specie. If adequate compensation is not made for these by-products, a significant drop in etch rate and an increase in contamination levels is typically noticed. As a result of this contamination, production lines would suffer from unpredictable wafer characteristics and hence lower cell efficiency.

In order to obtain stable and reproducible manufacturing processes, a reliable and accurate real-time measurement of the etching constituents becomes necessary. In addition, a mechanism by which fresh chemicals can be added to the etching bath is also required. The presence of these etch by-products has been shown to slow down the etch rate even when chemical concentration is correct. Simply put, the solubility of etch by-products decreases once the concentration of silicates increases. And hence, Si mass transport from wafer surface to the etching solution is impacted.

In this study, wafers were processed in a KOH/IPA mixture to produce texturized surfaces as shown in Figure 1. In-line sensors were installed to monitor the chemicals’ concentrations in real-time. Algorithms were developed to control the chemical concentration by injecting fresh chemicals and water at a desired time interval to compensate for the loss of chemicals and water. The system also allows for draining and replenishing chemicals and water to keep the silicates under a threshold to maintain consistent etching characteristics under different bath loading conditions.

II. EXPERIMENTAL

Wet chemical processes were conducted on a fully-automated GAMASolar™ wafer etching and cleaning station. The batch size was 200 wafers per run. All tests were performed with the same wafer supplier, including wafers from about 100 different ingots. Silicon etching processes were conducted with the aid of Akrion Systems' patented in-
situ chemical concentration control system (ICE-1™). Measurements of concentrations were taken using inline NIR (near Infra-Red) sensors installed in the recirculation loop of the process tanks. These sensors measure light absorbance and transmit it through fiber optics cables to an array of detectors (spectrophotometer).

The light absorbance of given species in the solution is correlated to its concentration over a wide range of wavelengths. The signal is then reported to an amplifier that scales the response to a 4-20 mA output. This signal is subsequently fed into an analog module that scales the signal and reports directly to the system computer which controls the spiking (volumes and frequency) of chemicals to maintain concentration. A variety of chemicals e.g. HF, HNO₃, HAc and applications were also studied but only the results of KOH/IPA control will be presented here. The goal was to produce consistent etch rates and texturization patterns similar to those shown in Fig. 1 over the entire bath life and different silicon loading levels.

III. RESULTS AND DISCUSSION

This technology provides technical advantages by accurately measuring the concentration of chemicals to produce the desired process results - in this case the texturization pattern [1-3]. Controlling concentration for uniform, repeatable texturization will help solar cell manufacturers reduce cost of ownership (COO) and overall cost of manufacturing by extending the usable life of the chemical bath, which in turn extends the up-time and overall utilization of the tool [4-5].

Fig. 2 shows the calibration curve of the concentration of KOH. Similar calibration is typically run for IPA. Fig. 3 shows the amount of KOH that is required to maintain a stable etch rate over time. As can be seen from Figure 3, the volume of KOH required for maintaining a constant etch rate (ER) is linearly related to the mass of Si being etched. The data is in excellent agreement with stoichiometry and stands on good grounds for production applications. The system is also calibrated to track the etch byproducts (measured as Si) as shown in Fig. 4.

Results have shown that the dissolved Si in the bath must be maintained below a threshold limit. Akrion Systems has implemented an algorithm to control Si concentration in the bath as well, so the etch rate is maintained. This algorithm allows the capability to spike known volumes of fresh chemicals and drain out old chemicals. The system is therefore able to maintain the concentrations of chemicals as well as the etch by-products. As a result, consistent wafer processing as shown in Fig. 5 and 6 for reflectance and Si etch rate, respectively, is achieved. Fig. 5 shows that the reflectance was well below 10% for the majority of the runs despite different loading conditions. Pyramids’ sizes ranged from 8-12 µm for all runs. This is particularly important for the cell manufacturing where the film deposition and integrity require uniform texturization in size and pattern.

Unstable etch rate was shown before in the case when no ICE control was used as can be seen from Fig. 7. Longer utilization of the bath and lower cost of ownership is easily attained.
IV. CONCLUSIONS

Results show that real-time chemical concentration monitoring and control are critical and beneficial for advanced solar cell manufacturing. The technology reduces the days required for field installation by eliminating the time and resources required to dial-in the right chemicals' concentrations.

Utilizing closed loop concentration control, this process will no longer require many iterations and tedious work until the results are achieved. The technology significantly reduces rework and wafer miss-processing and hence the manufacturing becomes more robust and less costly.

REFERENCES


